L Number	Hits	Search Text	DB	Time stamp	
1	2	gate adj area same protection same diode	USPAT; US-PGPUB; EPO; JPO;	2003/09/15 11:03	
2	4	5913120.URPN.	DERWENT; IBM_TDB USPAT	2003/09/15	
3	6	("4635347" "4719184" "4775642" "5036018" "5183773" "5466622").PN.	USPAT	2003/09/15	
4	0	gate adj area same protection same diode near size	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/15 11:03	
5	16	protection same diode near size	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/15 11:14	
6	5753259	signal near\$3 line same diode near\$3 size	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/15 11:16	
7	12	signal near3 line same diode near3 size	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/15 11:25	
8	26	esd same diode near3 size	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/15	
19	2	5910730.pn.	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/09/15 15:51	
-	646	IC same signal same line same buffer	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/15 10:56	
_	2	IC same signal same long near line same buffer	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/05 09:53	
_	50	IC same signal same line same buffer same delay	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/08	
_	0	IC same signal same line same buffer same delay same protect\$	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/05	
-	25	IC same signal same line same buffer same protect\$	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/09/05 10:10	
_	3	IC same signal same line same buffer same protect\$ same diode	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/05 14:00	

Search History 9/15/03 4:02:31 PM Page 1

-	190	rule adj checker	USPAT;	2003/09/05
			US-PGPUB;	14:01
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
l _	3	rule adj checker same buffer	USPAT;	2003/09/05
			US-PGPUB;	14:03
			EPO; JPO;	
			DERWENT;	
1			IBM TDB	
			USPAT;	2003/09/05
-	1	1		
		diode	US-PGPUB;	14:04
	ļ		EPO; JPO;	L.
			DERWENT;	
			IBM_TDB	
-	499	buffer same protection same diode	USPAT;	2003/09/05
			US-PGPUB;	14:04
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
l _	135	buffer same protection same diode same	-	2003/09/05
1 -	133		US-PGPUB;	14:05
		(IC mosfet fet mos)		13.00
			EPO; JPO;	1
Ī			DERWENT;	1
			IBM_TDB	
-	27			2003/09/05
		(IC mosfet fet mos) same charge	US-PGPUB;	14:05
1			EPO; JPO;	
			DERWENT;	1
			IBM TDB	
1_	207	antenna adj ratio	USPAT;	2003/09/05
	1 207	discount and races	US-PGPUB;	14:41
			EPO; JPO;	
			DERWENT;	
	_		IBM_TDB	2003/00/05
-	1	antenna adj ratio same fet	USPAT;	2003/09/05
			US-PGPUB;	14:41
			EPO; JPO;	
1			DERWENT;	
1			IBM_TDB	
_	2	"20030081361"	USPAT;	2003/09/08
			US-PGPUB;	11:04
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	6	IC same signal same line same buffer	USPAT;	2003/09/08
-	"		US-PGPUB;	15:54
		same esd	<u> </u>	10.04
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	1 0000 (00 (00
-	36	IC same signal same line same esd	USPAT;	2003/09/08
			US-PGPUB;	16:06
			EPO; JPO;	1
			DERWENT;	1
			IBM TDB	
_	4	("4876584" "4989057").pn.	USPAT;	2003/09/08
	1	,, , , , , , , , , , , , , , , , ,	US-PGPUB;	16:06
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
		222/154		12002/00/10
_	258	333/164.ccls.	USPAT;	2003/09/10
			US-PGPUB;	13:17
			EPO; JPO;	
			DERWENT;	1
			IBM_TDB	1
-	9	333/164.ccls. and buffer	USPAT;	2003/09/10
	1		US-PGPUB;	13:17
			EPO; JPO;	
1				I
			DERWENT:	
			DERWENT; IBM TDB	

			Trans-	2002/00/22
-	10	esd same gate adj area	USPAT; US-PGPUB;	2003/09/11 10:04
			EPO; JPO;	10.03
			DERWENT;	
			IBM_TDB	
-	2	esd same (gate adj area same size)	USPAT;	2003/09/11
			US-PGPUB;	10:06
			EPO; JPO; DERWENT;	
			IBM TDB	
-	2	esd same gate adj area and (diode same	USPĀT;	2003/09/11
		size)	US-PGPUB;	10:09
			EPO; JPO; DERWENT;	
			IBM TDB	
-	96	Buffer same bjt	USPAT;	2003/09/11
			US-PGPUB;	10:10
			EPO; JPO;	
			DERWENT; IBM TDB	
_	4	Buffer same bjt same esd	USPAT;	2003/09/11
	_		US-PGPUB;	10:33
			EPO; JPO;	
			DERWENT; IBM TDB	
_	180	Buffer same pfet same nfet	USPAT;	2003/09/11
		Table band prod band into	US-PGPUB;	10:33
			EPO; JPO;	
			DERWENT;	
	2	Buffer same pfet same nfet same esd	IBM_TDB USPAT;	2003/09/11
_		parrer same bree same mree same esa	US-PGPUB;	13:35
			EPO; JPO;	
			DERWENT;	
	F ~	Buffey came introduce	IBM_TDB	2003/09/11
_	59	Buffer same inverter same esd	USPAT; US-PGPUB;	2003/09/11
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/00/11
-	83	Buffer same inverter same pfet same nfet	USPAT; US-PGPUB;	2003/09/11 15:48
			EPO; JPO;	13.40
			DERWENT;	
			IBM_TDB	0000/00/00
-	29	Buffer same pfet same nfet same inverters	USPAT;	2003/09/11 13:36
			US-PGPUB; EPO; JPO;	13.30
			DERWENT;	
			IBM_TDB	
-	11	Buffer same inverter same bjt	USPAT;	2003/09/11
			US-PGPUB; EPO; JPO;	15:49
			DERWENT;	
			IBM_TDB	
-	0	Buffer same inverter same bjt same esd	USPAT;	2003/09/11
			US-PGPUB;	15:50
			EPO; JPO; DERWENT;	
			IBM TDB	
-	2	Buffer same inverter same bjt and esd	USPĀT;	2003/09/11
			US-PGPUB;	15:50
			EPO; JPO; DERWENT;	
			IBM TDB	
-	21	size near4 protection near4 Diode	USPAT;	2003/09/11
			US-PGPUB;	16:51
			EPO; JPO; DERWENT;	
			IBM TDB	
	L	I		l



-	4	size n	ear4	protection	near4	Diode	same	USPAT;	2003/09/11
		esd						US-PGPUB;	16:52
								EPO; JPO;	
	i							DERWENT;	
								IBM_TDB	